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#### January 2006

### FAIRCHILD

SEMICONDUCTOR®

# FDB8445

# N-Channel PowerTrench<sup>®</sup> MOSFET 40V, 70A, 9m $\Omega$

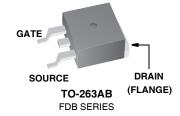
#### Features

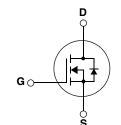
- Typ  $r_{DS(on)}$  = 6.8m $\Omega$  at V<sub>GS</sub> = 10V, I<sub>D</sub> = 70A
- Typ Q<sub>g(10)</sub> = 44nC at V<sub>GS</sub> = 10V
- Low Miller Charge
- Low Q<sub>rr</sub> Body Diode
- UIS Capability (Single Pulse/ Repetitive Pulse)
- Qualified to AEC Q101
- RoHS Compliant

### Applications

- Automotive Engine Control
- Powertrain Management
- Solenoid and Motor Drivers
- Electronic Transmission
- Distributed Power Architecture and VRMs
- Primary Switch for 12V Systems







Absolute Maximum Ratings $T_{C}$ = 25°C unless otherwise noted					
Symbol	Parameter		Ratings	Units	
V <sub>DSS</sub>	Drain to Source Voltage		40	V	
V <sub>GS</sub>	Gate to Source Voltage		±20	V	
	Drain Current Continuous (V <sub>GS</sub> = 10V)	(Note 1)	70	Α	
D	Pulsed		Figure 4		
E <sub>AS</sub>	Single Pulse Avalanche Energy	(Note 2)	102	mJ	
C	Power Dissipation		92	W	
P <sub>D</sub>	Derate above 25°C		0.6	W/ºC	
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature		-55 to +175	°C	

# **Thermal Characteristics**

$R_{ ext{ heta}JC}$	Thermal Resistance, Junction to Case	1.63	°C/W
$R_{ hetaJA}$	Thermal Resistance, Junction to Ambient TO-263, 1in <sup>2</sup> copper pad area	43	°C/W

# Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDB8445	FDB8445	TO-263AB	330mm	24mm	800 units

# **Electrical Characteristics** $T_J$ = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units

#### **Off Characteristics**

B <sub>VDSS</sub>	Drain to Source Breakdown Voltage	I <sub>D</sub> = 250μA, V <sub>G</sub>	$I_{D}$ = 250µA, $V_{GS}$ = 0V		-	-	V
Voltage Drain Current		V <sub>DS</sub> = 32V		-	-	1	μA
I <sub>DSS</sub> Zero Gate Voltage Drain Current	$V_{GS} = 0V$	T <sub>J</sub> =150°C	-	-	250	μA	
I <sub>GSS</sub>	Gate to Source Leakage Current	$V_{GS}$ = ±20V		-	-	±100	nA

#### **On Characteristics**

V <sub>GS(th)</sub>	Gate to Source Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	2	2.5	4	V
		I <sub>D</sub> = 70A, V <sub>GS</sub> = 10V	-	6.8	9	
r <sub>DS(on)</sub>	Drain to Source On Resistance	$I_D = 70A, V_{GS} = 10V, T_J = 175^{\circ}C$	-	13	17.2	mΩ

#### Dynamic Characteristics

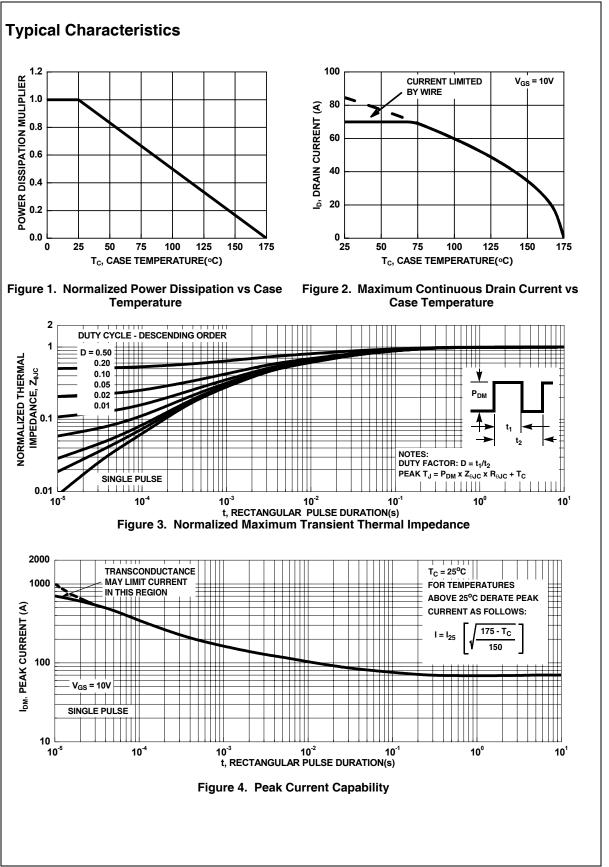
C <sub>iss</sub>	Input Capacitance		V <sub>DS</sub> = 25V, V <sub>GS</sub> = 0V, f = 1MHz		2860	3805	pF
C <sub>oss</sub>	Output Capacitance				295	395	pF
C <sub>rss</sub>	Reverse Transfer Capacitance				180	270	pF
R <sub>G</sub>	Gate Resistance	f = 1MHz		-	1.95	-	W
Q <sub>g(TOT)</sub>	Total Gate Charge at 10V	V <sub>GS</sub> = 0 to 10V		-	44	62	nC
Q <sub>g(TH)</sub>	Threshold Gate Charge	$V_{GS}$ = 0 to 2V	V <sub>DS</sub> =20V,	-	2.9	4.1	nC
Q <sub>gs</sub>	Gate to Source Gate Charge		I <sub>D</sub> = 70A,	-	11	-	nC
Q <sub>gs2</sub>	Gate Charge Threshold to Plateau			-	8.2	-	nC
Q <sub>gd</sub>	Gate to Drain Charge			-	11	-	nC

Symbol	Parameter	Test Conditions	Min	Тур	Мах	Units
Switching	g Characteristics					
t <sub>(on)</sub>	Turn-On Time		-	-	45	ns
t <sub>d(on)</sub>	Turn-On Delay Time		-	10	-	ns
t <sub>r</sub>	Turn-On Rise Time	V <sub>DD</sub> = 20V, I <sub>D</sub> = 70A	-	19	-	ns
t <sub>d(off)</sub>	Turn-Off Delay Time	$V_{DD} = 20V, I_D = 70A$ $V_{GS} = 10V, R_{GS} = 5\Omega$	-	36	-	ns
t <sub>f</sub>	Turn-Off Fall Time		-	16	-	ns
t <sub>off</sub>	Turn-Off Time		-	-	81	ns

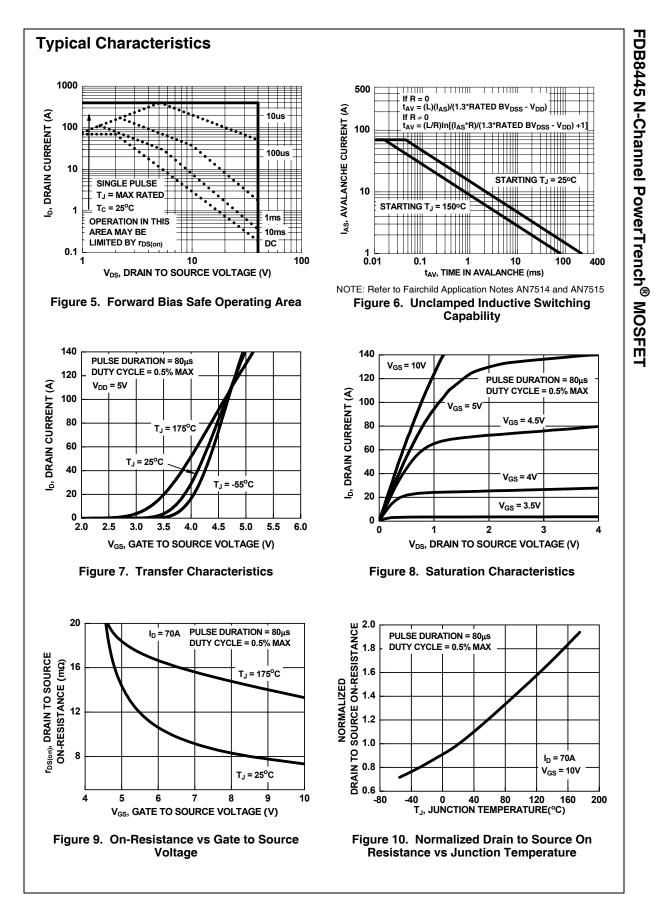
V		Source to Drain Diode Voltage	I <sub>SD</sub> = 70A	-	-	1.25	V
۷s	D	Source to Drain Diode voltage	I <sub>SD</sub> = 35A	-	-	1.0	V
t <sub>rr</sub>		Reverse Recovery Time	I <sub>F</sub> = 70A, di/dt = 100A/μs	-	-	59	ns
Q <sub>rr</sub>	r	Reverse Recovery Charge	I <sub>F</sub> = 70A, di/dt = 100A/μs	-	-	77	nC

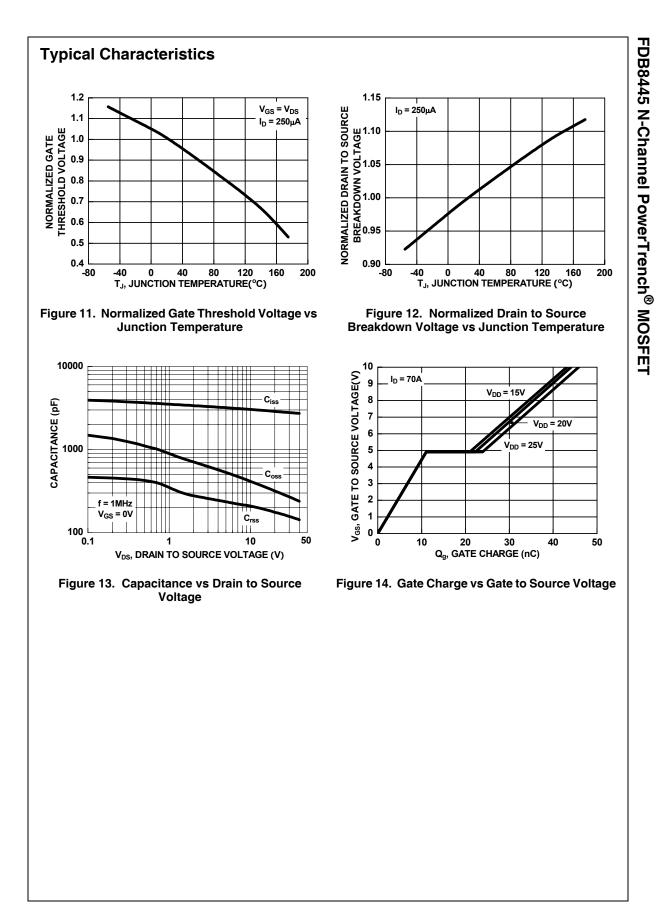
Notes: 1: Maximum wire current carrying capacity is 70A. 2: Starting  $T_J = 25^{\circ}C$ , L =  $65\mu$ H, I<sub>AS</sub> = 56A.

This product has been designed to meet the extreme test conditions and environment demanded by the automotive industry. For a copy of the requirements, see AEC Q101 at: http://www.aecouncil.com/ All Fairchild Semiconductor products are manufactured, assembled and tested under ISO9000 and QS9000 quality systems certification.



FDB8445 N-Channel PowerTrench<sup>®</sup> MOSFET





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Rev. 117

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